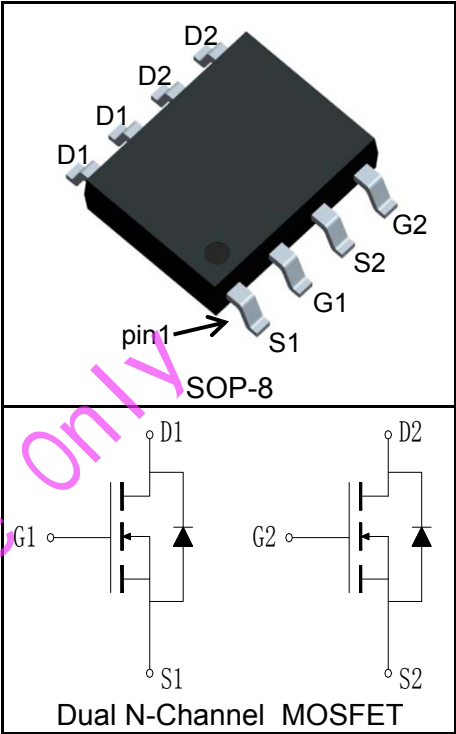


Features

- 30V/20A,
 $R_{DS(ON)}=10m\Omega(Typ.)@V_{GS}=10V$
 $R_{DS(ON)}=12m\Omega(Typ.)@V_{GS}=4.5V$
- Fast Switching Speed
- Low gate Charge
- 100% avalanche tested
- Lead Free and Green Devices Available (RoHS Compliant)

Pin Description



Applications

- Switching Application Systems

Absolute Maximum Ratings

Symbol	Parameter		Rating	Unit
Common Ratings (T _A =25°C Unless Otherwise Noted)				
V _{DSS}	Drain-Source Voltage		30	V
V _{GSS}	Gate-Source Voltage		±16	
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-55 to 150	°C
I _S	Diode Continuous Forward Current	T _A =25°C	20	A
Mounted on Large Heat Sink				
I _{DP} ^①	300µs Pulse Drain Current Tested	T _A =25°C	80	A
I _D ^②	Continuous Drain Current(V _{GS} =4.5V)	T _A =25°C	20	A
		T _A =70°C	13	
P _D	Maximum Power Dissipation	T _A =25°C	3.5	W
		T _A =70°C	2.3	
R _{θJC}	Thermal Resistance-Junction to Case		-	°C/W
R _{θJA} ^③	Thermal Resistance-Junction to Ambient		50	°C/W
Drain-Source Avalanche Ratings				
E _{AS} ^④	Avalanche Energy, Single Pulsed		-	mJ

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU30D20H			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =250μA	30			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V			1	μA
		T _J =125°C			30	
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250μA	1		2.5	V
I _{GSS}	Gate Leakage Current	V _{GS} =±16V, V _{DS} =0V			±100	nA
R _{DS(ON)} ^⑤	Drain-Source On-state Resistance	V _{GS} =10V, I _{DS} =10A		10	12	mΩ
		V _{GS} =4.5V, I _{DS} =8A		12	14	mΩ
Diode Characteristics						
V _{SD} ^⑤	Diode Forward Voltage	I _{SD} =20A, V _{GS} =0V			1.3	V
t _{rr}	Reverse Recovery Time	I _{SD} =20A, dI _{SD} /dt=100A/μs		24		ns
Q _{rr}	Reverse Recovery Charge			13		nC
Dynamic Characteristics ^⑥						
R _G	Gate Resistance	V _{GS} =0V, V _{DS} =0V, F=1MHz		1		Ω
C _{iSS}	Input Capacitance	V _{GS} =0V, V _{DS} =15V, Frequency=1.0MHz		930		pF
C _{oss}	Output Capacitance			230		
C _{rSS}	Reverse Transfer Capacitance			90		
t _{d(ON)}	Turn-on Delay Time	V _{DD} =15V, I _{DS} =20A, V _{GEN} =10V, R _G =3Ω		8		ns
t _r	Turn-on Rise Time			11		
t _{d(OFF)}	Turn-off Delay Time			17		
t _f	Turn-off Fall Time			6		
Gate Charge Characteristics ^⑥						
Q _g	Total Gate Charge	V _{DS} =24V, V _{GS} =10V, I _{DS} =20A		18		nC
Q _{gs}	Gate-Source Charge			5		
Q _{gd}	Gate-Drain Charge			7		

- Notes:
- ① Pulse width limited by safe operating area.
 - ② Calculated continuous current based on maximum allowable junction temperature.
 - ③ When mounted on 1 inch square copper board, $t \leq 10\text{sec}$. The value in any given application depends on the user's specific board design.
 - ④ Limited by T_{Jmax} . Starting $T_J = 25^{\circ}\text{C}$.
 - ⑤ Pulse test; Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
 - ⑥ Guaranteed by design, not subject to production testing.

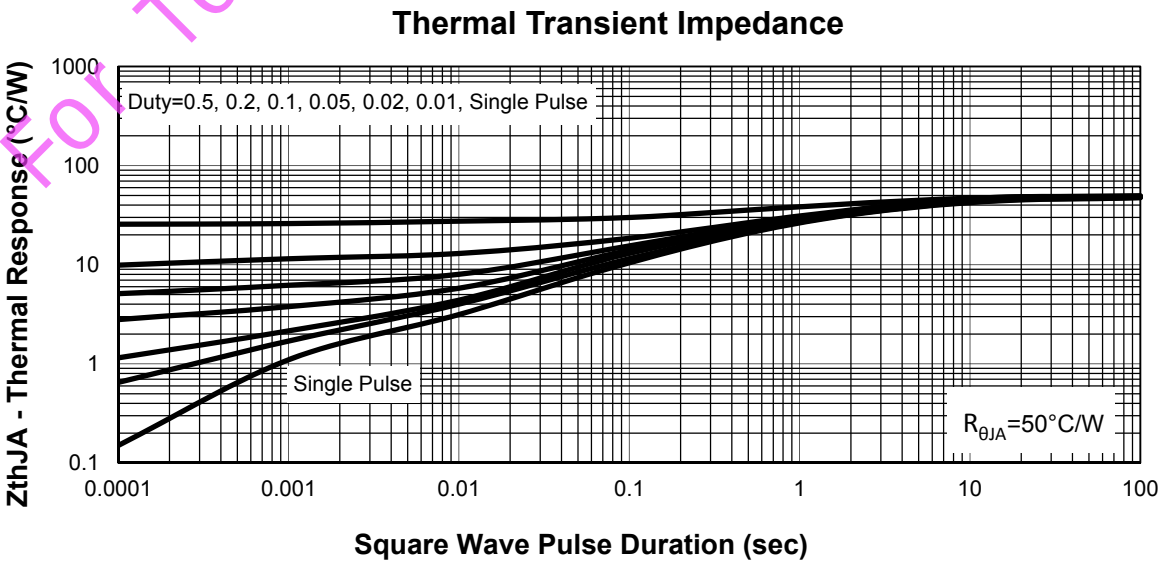
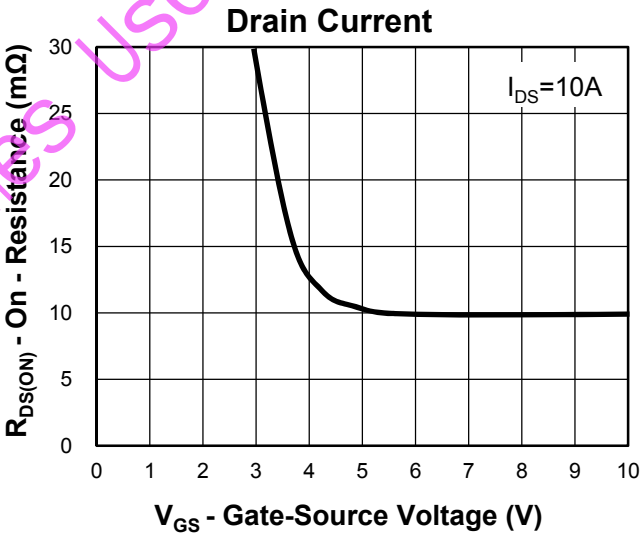
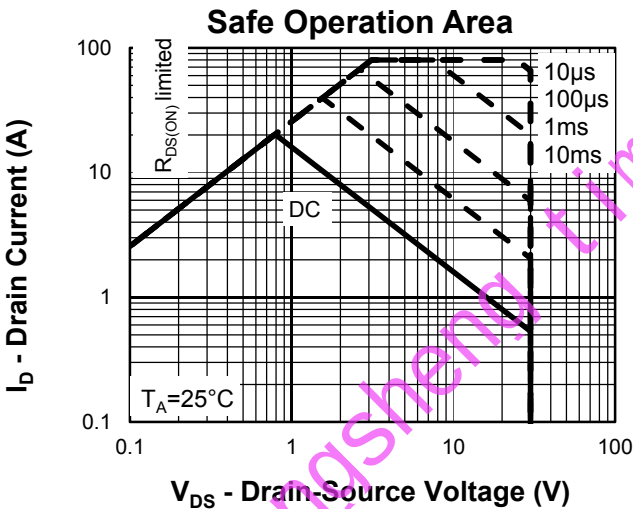
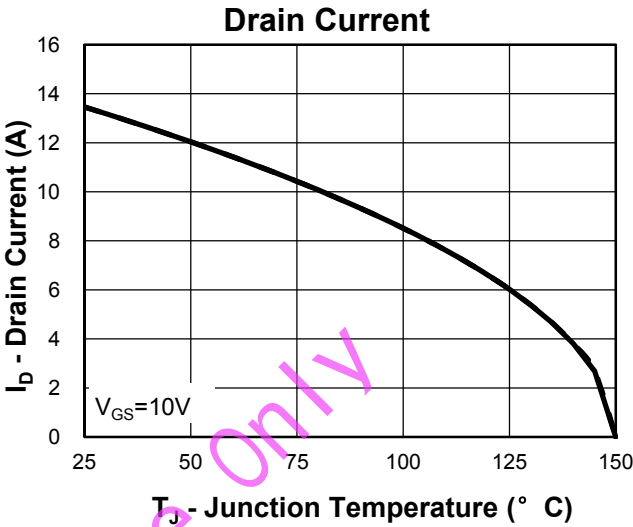
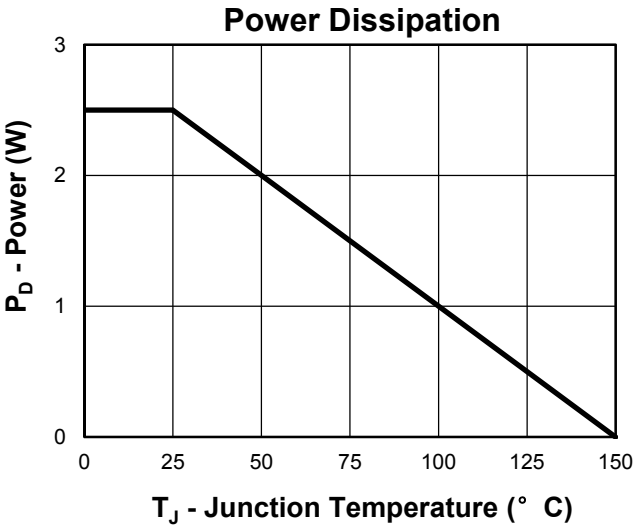


Ordering and Marking Information

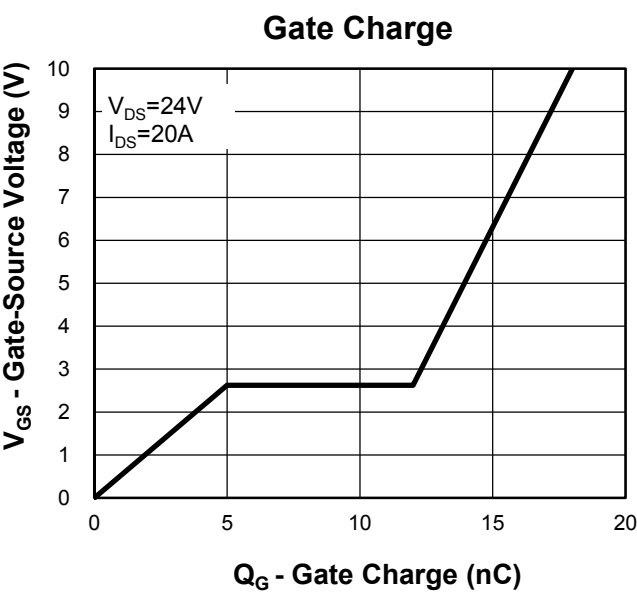
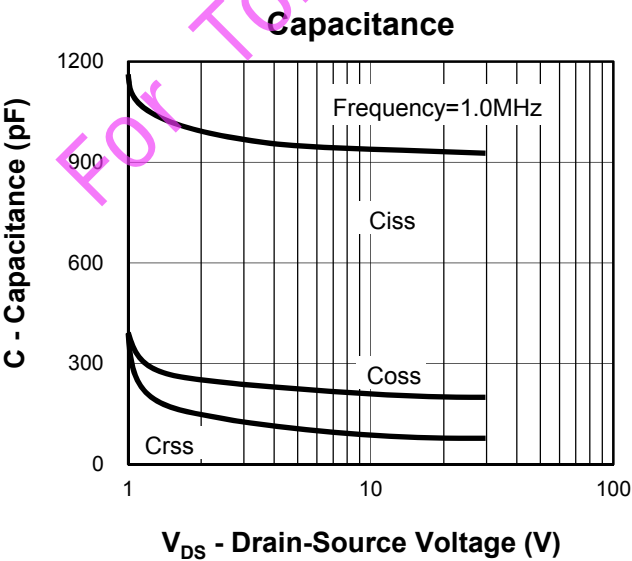
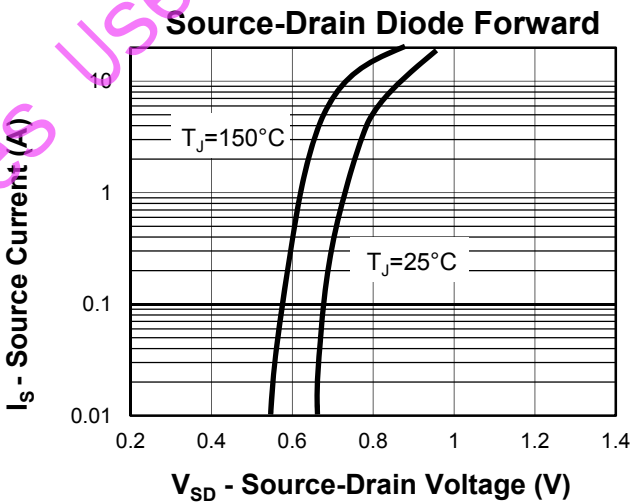
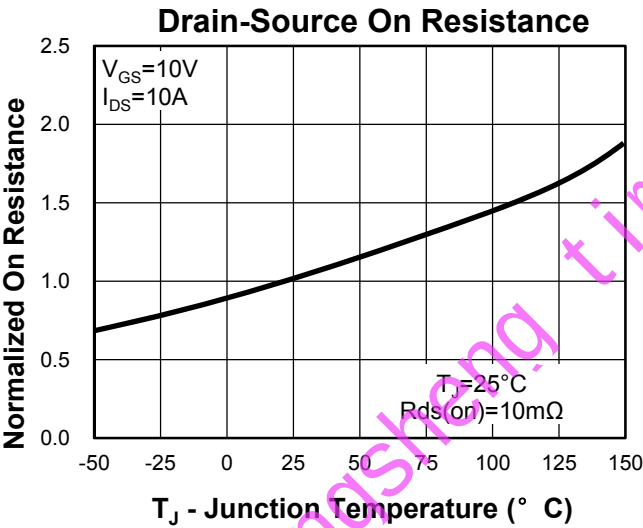
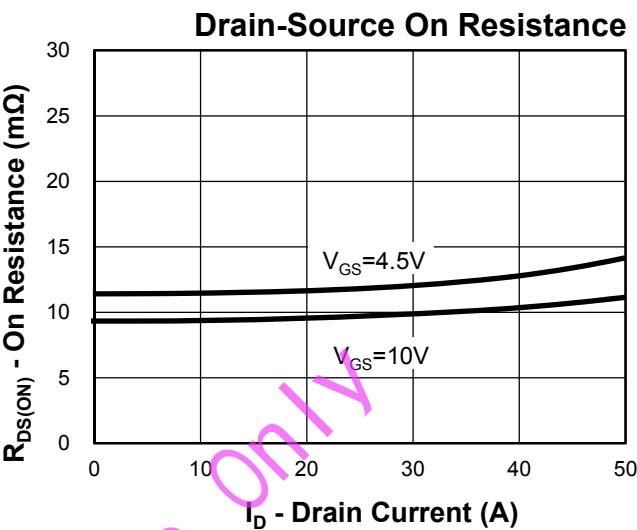
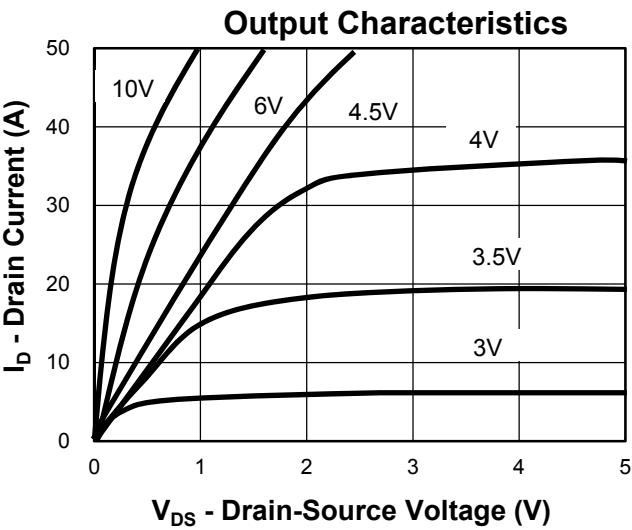
Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
RU30D20H	RU30D20H	SOP-8	Tape&Reel	2500	13"	12mm

For Tongsheng times Use Only

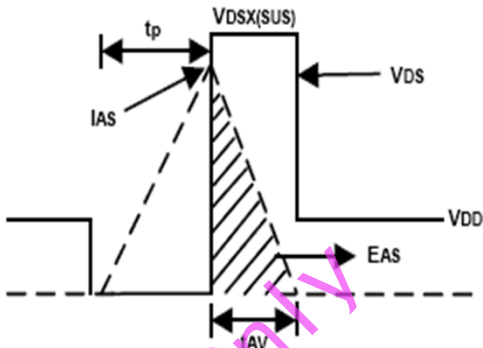
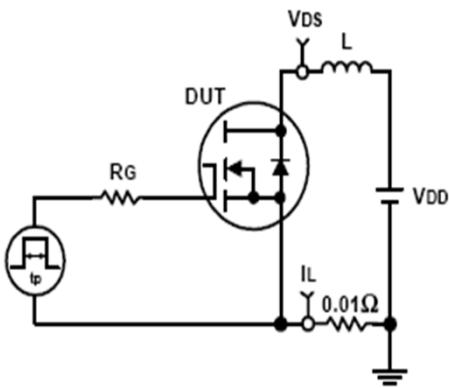
Typical Characteristics



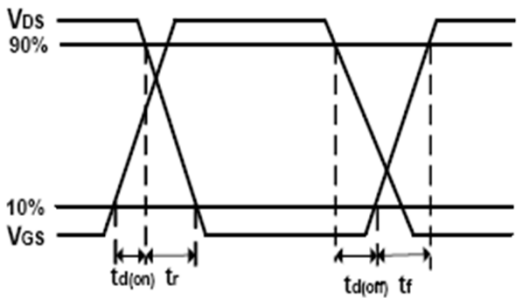
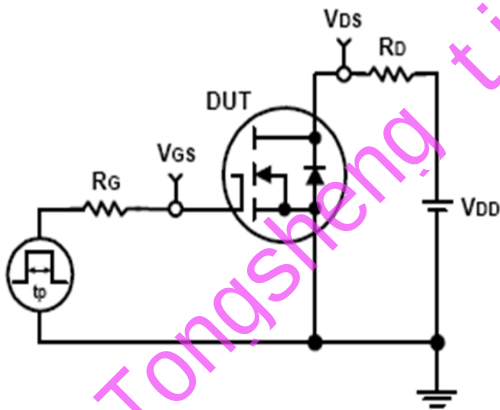
Typical Characteristics



Avalanche Test Circuit and Waveforms

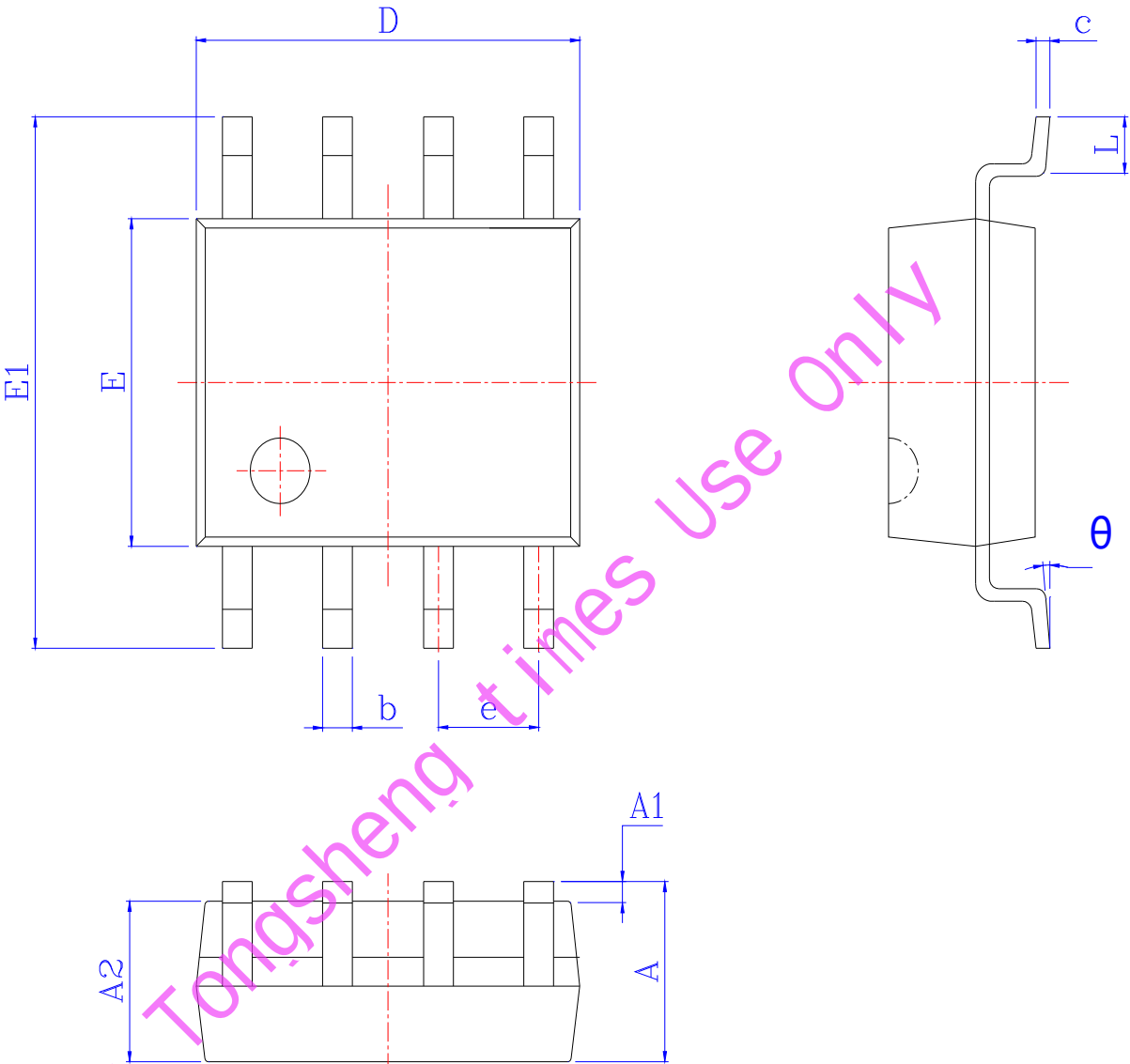


Switching Time Test Circuit and Waveforms



Package Information

SOP-8



SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.300	1.525	1.750	0.051	0.060	0.069
A1	0.050	0.150	0.250	0.002	0.006	0.010
A2	1.300	1.450	1.550	0.051	0.057	0.061
b	0.330	0.420	0.510	0.013	0.017	0.020
c	0.170	*	0.260	0.007	*	0.010
D	4.700	4.900	5.100	0.185	0.193	0.201
E	3.700	3.900	4.100	0.146	0.154	0.161
E1	5.800	6.000	6.200	0.228	0.236	0.244
e	1.270 BSC			0.050 BSC		
L	0.400	0.835	1.270	0.016	0.033	0.050
θ	0°	*	8°	0°	*	8°



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